# **Supplementary Information**

# A promising nanohybrid of silicon carbide nanowires scrolled by graphene oxide sheets with synergistic effect for poly(propylene carbonate) nanocomposites

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## Dispersion amount of SiC nanowires in the SiC/GO suspension

The SiC/GO dispersions with the concentration of 2 mg ml<sup>-1</sup> was estimated by weighting the amount of the dispersed solid (upper layer after standing overnight) after evaporation process. The content of SiC nanowires in the resulting SiC/GO dispersed solid was then analyzed by TGA. The dispersion amount of SiC was calculated using equations: Y=M<sub>u</sub>/M<sub>o</sub>. Where M<sub>u</sub> is the content of SiC nanowires in the upper layer of SiC/GO suspension, M<sub>o</sub> is the content of SiC nanowires in the original SiC/GO suspension. The dispersion amount of SiC means the amount of SiC dispersed by GO sheets. Dispersion stability was studied by UV-*vis* absorption spectra as shown in **Figure S1**.



**Figure S1**. UV-*vis* absorption spectra of (a) GO and (b) SiC-GO 3 hybrid dispersed in water with different concentrations; (c) optical density at 500 nm of SiC-GO and GO at different concentrations.

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#### Hydrogen interactions between GO and SiC

We assumed that the abundant oxygen groups of GO interact with the surface hydroxyl groups of SiC through hydrogen bonding, and then a SiC/GO scroll-like structure was formed. The hydrogen bonding was analyzed by FTIR in this study and result was presented in **Figure S2**. For the convenience of observation, the weight ratio of GO to SiC (GO/SiC=0-50) used in the mixture are different from that used for the fabrication of composites (GO/SiC=1). **Figure S2 (a)** shows that the interactions between SiC and GO weaken the interaction of GO itself, so the frequencies of peak at 1618 cm<sup>-1</sup> corresponding to the C=O bonds present in GO is slightly shifted towards high wavenumbers with increasing amount of SiC in the GO/SiC nanohybrid. Additionally, **Figure S2 (b)** shows the peak at 941 cm<sup>-1</sup> corresponding to the O-H bonds of SiC were lowered (4-5 cm<sup>-1</sup>) by the increasing amount of GO in the SiC/GO nanohybrid. These results indicate that the interactions between OH groups of SiC and COOH groups of GO weaken the interactions of GO itself, which is in a good agreement with our morphological observation for the SiC/GO nanohybrids.



**Figure S2**. FTIR spectra of (a) GO and nanohybrids with different GO/SiC ratios; (b) SiC and nanohybrids with different SiC/GO ratios.

Tensile properties of neat PPC and PPC-SiC/GO nanocomposites



**Figure S3**. Tensile properties of neat PPC and PPC-SiC/GO nanocomposites composites with different filler contents.

#### Theoretical values of tensile modules of PPC-based nanocomposites

The SiC nanowires composites were considered as random oriented discontinuous fibers, and the GO sheets were assumed as effective rectangular solid fibers, the modulus of the PPC-SiC and PPC-GO composites can be calculated from the Equations S1 and S2, respectively.

#### **PPC-SiC composite:**

$$E_{c} = \frac{3}{8} \frac{1 + 2\left(\frac{l_{NT}}{d_{NT}}\right) \left[\frac{E_{R} - 1}{E_{R} + 2\left(l_{NT}/d_{NT}\right)}\right]}{1 - \left[\frac{E_{R} - 1}{E_{R} + 2\left(l_{NT}/d_{NT}\right)}\right]} \times E_{M} + \frac{5}{8} \frac{1 + 2\left[\frac{E_{R} - 1}{E_{R} + 2}\right] V_{NT}}{1 - \left[\frac{E_{R} - 1}{E_{R} + 2}\right] V_{NT}} \times E_{M}$$
 S1

In the Halpin–Tsai model,  $E_c$  is the tensile modulus of the composite,  $I_{NT}$  is the length of nanowires (100 µm),  $d_{NT}$  is the average diameter of the nanotubes (300 nm),  $E_R = E_{eq}/E_M$ ,  $E_{eq}$  is the equivalent modulus of nanowires (581 GPa),  $E_M$  is the tensile modulus of PPC matrix (3.03GPa) and  $V_{NT}$  is the volume content of the nanowires.

## **PPC-GO composite:**

$$E_{c} = \frac{3}{8} \frac{1 + \left( \left( \frac{W}{L} \right) / t \right) \left[ \frac{E_{r} - 1}{E_{r} + \left( \frac{W}{L} \right) / t \right)} \right] V_{GPL}}{1 - \left[ \frac{E_{r} - 1}{E_{r} + \left( \frac{W}{L} \right) / t \right)} \right] V_{GPL}} \times E_{M} + \frac{5}{8} \frac{1 + 2 \left[ \frac{E_{r} - 1}{E_{r} + 2} \right] V_{GPL}}{1 - \left[ \frac{E_{r} - 1}{E_{r} + 2} \right] V_{GPL}} \times E_{M}$$
 S2

In the modified Halpin–Tsai model,  $E_c$  is the tensile modulus of the composite, W is the

average width of GO sheets (5  $\mu$ m), *L* is the average length of the GO sheets (5 $\mu$ m), *t* is the average thickness of GO sheets (1.1nm),  $E_r = E_{GPL}/E_M$ ,  $E_{GPL}$  is the equivalent modulus of GO sheets (1.11 TPa),  $E_M$  is the tensile odulus of PPC matrix (3.03 GPa) and  $V_{GPL}$  is the volume content of the GO sheets.

The  $V_{NT}$  and  $V_{GPL}$  in equation S1 and S2 can be calculated from wt % of SiC nanowires and GO sheets, respectively.